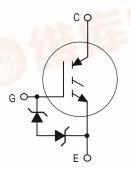
Designer's™ Data Sheet

Insulated Gate Bipolar Transistor

N-Channel Enhancement-Mode Silicon Gate

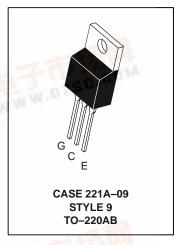
This Insulated Gate Bipolar Transistor (IGBT) uses an advanced termination scheme to provide an enhanced and reliable high voltage—blocking capability. Its new 600 V IGBT technology is specifically suited for applications requiring both a high temperature short circuit capability and a low VCE(on). It also provides fast switching characteristics and results in efficient operation at high frequencies. This new E—series introduces an energy efficient, ESD protected, and short circuit rugged device.

- Industry Standard TO–220 Package
- High Speed: E_{off} = 60 μJ/A typical at 125°C
- High Voltage Short Circuit Capability 10 μs minimum at 125°C, 400 V
- Low On-Voltage 2.0 V typical at 8.0 A, 125°C
- Robust High Voltage Termination
- ESD Protection Gate-Emitter Zener Diodes



MGP11N60E

IGBT IN TO-220 11 A @ 90°C 15 A @ 25°C 600 VOLTS SHORT CIRCUIT RATED LOW ON-VOLTAGE



MAXIMUM RATINGS (T_{.J} = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	VCES	600	Vdc	
Collector–Gate Voltage ($R_{GE} = 1.0 \text{ M}\Omega$)	VCGR	600	Vdc	
Gate-Emitter Voltage — Continuous	V _{GE}	±20	Vdc	
Collector Current — Continuous @ T _C = 25°C — Continuous @ T _C = 90°C — Repetitive Pulsed Current (1)	I _{C25} I _{C90} I _{CM}	15 11 22	Adc Apk	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	96 0.77	Watts W/°C	
Operating and Storage Junction Temperature Range	T _J , T _{Stg}	-55 to 150	°C	
Short Circuit Withstand Time (V _{CC} = 400 Vdc, V _{GE} = 15 Vdc, T _J = 125°C, R _G = 20 Ω)	t _{sc}	10	μS	
Thermal Resistance — Junction to Case – IGBT — Junction to Ambient	R _θ JC R _θ JA	1.3 65	°C/W	
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C	
Mounting Torque, 6–32 or M3 screw	10	10 lbf•in (1.13 N•m)		

⁽¹⁾ Pulse width is limited by maximum junction temperature. Repetitive rating.

Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

Designer's is a trademark of Motorola, Inc.





MGP11N60E

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted)

Cha	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector-to-Emitter Breakdown Vo (VGE = 0 Vdc, I _C = 25 µAdc) Temperature Coefficient (Positive	V(BR)CES	600 —	— 870	_	Vdc mV/°C	
Emitter-to-Collector Breakdown Vo	V _{(BR)ECS}	15	_	_	Vdc	
Zero Gate Voltage Collector Currer (V _{CE} = 600 Vdc, V _{GE} = 0 Vdc) (V _{CE} = 600 Vdc, V _{GE} = 0 Vdc, T	ICES	_ _ _	_ _	10 200	μAdc	
Gate-Body Leakage Current (VGE	IGES	_	_	50	μAdc	
ON CHARACTERISTICS (1)		•				•
Collector-to-Emitter On-State Voltage (VGE = 15 Vdc, IC = 4.0 Adc) (VGE = 15 Vdc, IC = 4.0 Adc, T _J = 125°C) (VGE = 15 Vdc, I _C = 8.0 Adc) Gate Threshold Voltage (VCE = VGE, I _C = 1.0 mAdc)		VCE(on)	4.0	1.6 1.5 2.0 6.0 10	1.9 — 2.4 8.0	Vdc Vdc mV/°C
Threshold Temperature Coefficie Forward Transconductance (VCE =		Ot-		3.5		Mhos
DYNAMIC CHARACTERISTICS	- 10 vac, 1C = 0.0 Ado)	9fe		3.3		IVIIIOS
Input Capacitance		C _{ies}	_	779	_	pF
Output Capacitance	$(V_{CE} = 25 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{oes}	_	81	_	1
Transfer Capacitance	1 – 1.0 IVII 12)	C _{res}	_	13	_	1
SWITCHING CHARACTERISTICS (1)			ı		
Turn-On Delay Time		^t d(on)	_	46	_	ns
Rise Time	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 8.0 \text{ Adc},$	t _r	_	34	_	
Turn-Off Delay Time	V_{GE} = 15 Vdc, L = 300 μH, R_{G} = 20 Ω)	td(off)	_	102	_	
Fall Time	Energy losses include "tail"	t _f	_	226	_	
Turn-Off Switching Loss		E _{off}	_	0.32	0.40	mJ
Turn-On Delay Time		^t d(on)	_	42	_	ns
Rise Time	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 8.0 \text{ Adc},$	t _r	_	26	_]
Turn-Off Delay Time	V _{GE} = 15 Vdc, L = 300 μH R _G = 20 Ω, T _J = 125°C)	td(off)	_	214	_	
Fall Time	Energy losses include "tail"	t _f	_	228	_	
Turn-Off Switching Loss		E _{off}	_	0.48	_	mJ
Gate Charge		QT	_	39.2	_	nC
	$V_{CC} = 360 \text{ Vdc}, I_{C} = 8.0 \text{ Adc},$ $V_{GE} = 15 \text{ Vdc})$	Q ₁	_	8.7	_]
	GL	Q ₂	_	17.4	_	
INTERNAL PACKAGE INDUCTANO	E					
Internal Emitter Inductance (Measured from the emitter lead 0.25" from package to emitter bond pad)		LE	_	7.5	_	nH

⁽¹⁾ Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

MGP11N60E

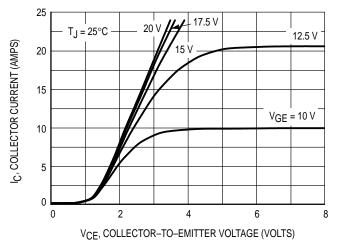


Figure 1. Output Characteristics

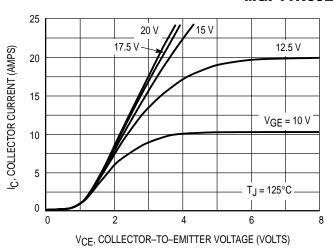


Figure 2. Output Characteristics

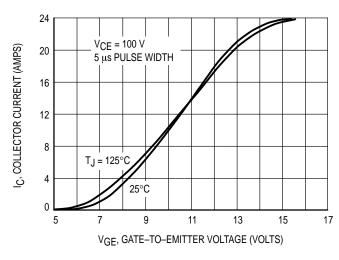


Figure 3. Transfer Characteristics

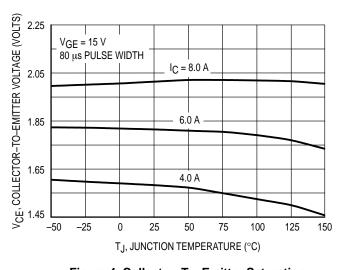


Figure 4. Collector–To–Emitter Saturation Voltage versus Junction Temperature

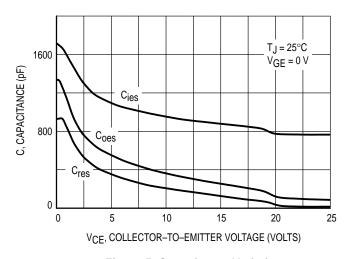


Figure 5. Capacitance Variation

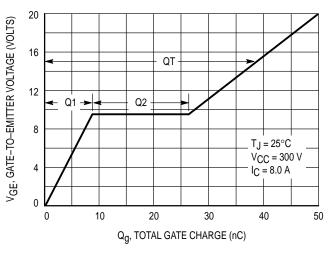


Figure 6. Gate—To—Emitter Voltage versus
Total Charge

MGP11N60E

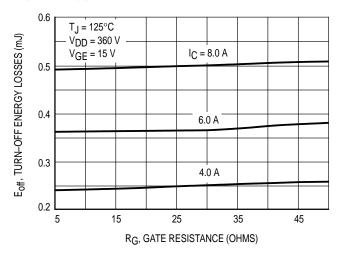


Figure 7. Turn–Off Losses versus
Gate Resistance

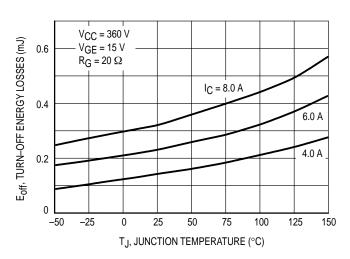


Figure 8. Turn-Off Losses versus Junction Temperature

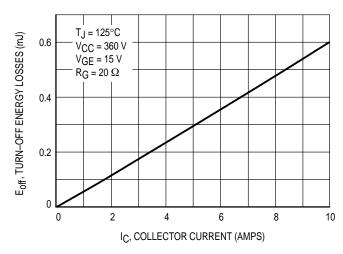


Figure 9. Turn-Off Losses versus Collector Current

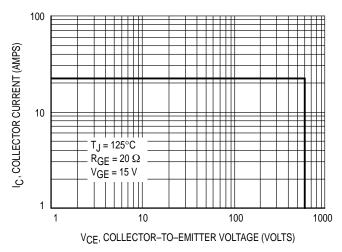
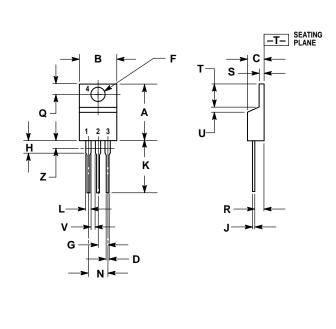


Figure 10. Reverse Biased Safe Operating Area

PACKAGE DIMENSIONS



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

STYLE 9: PIN 1.

GATE

COLLECTOR 3.

EMITTER COLLECTOR

CASE 221A-09 TO-220AB **ISSUE Z**

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